

CMPSH05-4
SURFACE MOUNT
HIGH CURRENT, LOW V_F
SILICON SCHOTTKY DIODE



SOT-23 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMPSH05-4 is a HIGH CURRENT, LOW V_F 40 volt Schottky Diode packaged in a space saving SOT-23 surface mount case. This device has been designed for small signal general purpose applications when small size and operational efficiency are prime requirements.

MARKING CODE: C054

FEATURES:

- Low V_F = 0.35V max @ 100mA
- V_{RRM} = 40V
- I_F = 500mA

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Peak Repetitive Reverse Voltage
Continuous Forward Current
Peak Repetitive Forward Current, $t_p \leq 1.0\text{ms}$
Peak Forward Surge Current, $t_p = 8.0\text{ms}$
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_{RRM}	40	V
I_F	500	mA
I_{FRM}	3.5	A
I_{FSM}	10	A
P_D	350	mW
T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Θ_{JA}	357	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

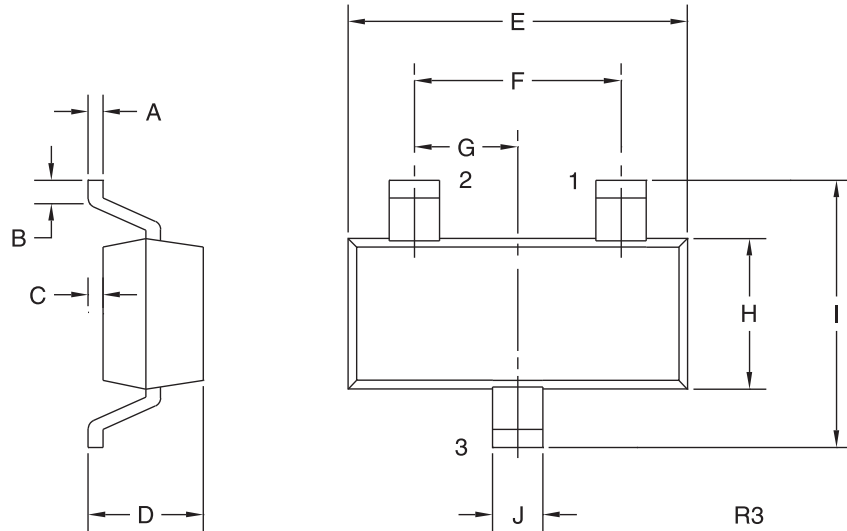
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_R	$V_R=10\text{V}$		20	μA
I_R	$V_R=30\text{V}$		100	μA
BV_R	$I_R=500\mu\text{A}$	40		V
V_F	$I_F=100\mu\text{A}$		0.13	V
V_F	$I_F=1.0\text{mA}$		0.21	V
V_F	$I_F=10\text{mA}$		0.27	V
V_F	$I_F=100\text{mA}$		0.35	V
V_F	$I_F=500\text{mA}$		0.47	V
C_T	$V_R=1.0\text{V}, f=1.0\text{MHz}$		50	pF

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SOT-23 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Anode
- 2) No Connection
- 3) Cathode

MARKING CODE: C054

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.003	0.007	0.08	0.18
B	0.006	-	0.15	-
C	-	0.005	-	0.13
D	0.035	0.043	0.89	1.09
E	0.110	0.120	2.80	3.05
F	0.075		1.90	
G	0.037		0.95	
H	0.047	0.055	1.19	1.40
I	0.083	0.098	2.10	2.49
J	0.014	0.020	0.35	0.50

SOT-23 (REV: R3)

R1 (27-January 2010)